

INA19x 共模电压范围为 -16V 至 +80V 的分流监测计

1 特性

- 宽共模电压范围：
-16V 至 +80V
- 低误差：3.0%（整个温度范围内的最大值）
- 带宽：高达 500kHz
- 三种传递函数：20V/V、50V/V 和 100V/V
- 静态电流：900 μ A（最大值）
- 完整的电流感测解决方案

2 应用

- 焊接设备
- 笔记本电脑
- 手机
- 电信设备
- 汽车用
- 电源管理
- 电池充电器

3 说明

INA193–INA198 系列是电压输出分流监测计，能够在 -16V 至 +80V 范围内的共模电压下感测分流器两端的压降，与 INA19x 电源电压无关。这些器件均提供三种输出电压级别：20V/V、50V/V 和 100V/V。500kHz 带宽方便用于电流控制回路。INA193–INA195 器件与 INA196–INA198 器件的功能相同，但引脚配置有所不同。

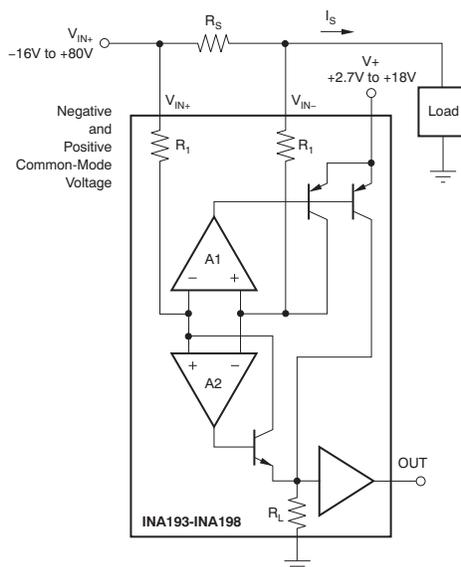
INA193-INA198 器件由 2.7V 至 18V 的单电源供电，最大供电电流为 900 μ A。这些器件均在 -40°C 至 +125°C 的扩展运行温度范围内额定运行，并且采用节省空间的 SOT-23 封装。

器件信息⁽¹⁾

器件型号	封装	封装尺寸（标称值）
INA193	SOT-23 (5)	2.90mm x 1.60mm
INA194		
INA195		
INA196		
INA197		
INA198		

(1) 要了解所有可用封装，请见数据表末尾的可订购产品附录。

LP38690 的



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4 修订历史记录

注：之前版本的页码可能与当前版本有所不同。

Changes from Revision F (February 2010) to Revision G	Page
<ul style="list-style-type: none"> Added <i>ESD Ratings</i> table, <i>Feature Description</i> section, <i>Device Functional Modes</i>, <i>Application and Implementation</i> section, <i>Power Supply Recommendations</i> section, <i>Layout</i> section, <i>Device and Documentation Support</i> section, and <i>Mechanical, Packaging, and Orderable Information</i> section 	4

Changes from Revision E (August 2006) to Revision F	Page
<ul style="list-style-type: none"> 已按照最新标准更新了文档格式 	1
<ul style="list-style-type: none"> Added test conditions to Output, <i>Total Output Error</i> parameter in Electrical Characteristics: $V_S = +12V$ 	5

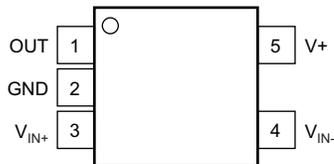
5 Device Comparison Table

PART NUMBER	GAIN	PINOUT ⁽¹⁾
INA193	20 V/V	Pinout #1
INA194	50 V/V	Pinout #1
INA195	100 V/V	Pinout #1
INA196	20 V/V	Pinout #2
INA197	50 V/V	Pinout #2
INA198	100 V/V	Pinout #2

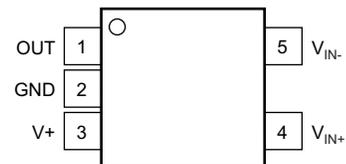
(1) See [Pin Configuration and Functions](#) for Pinout #1 and Pinout #2.

6 Pin Configuration and Functions

**DBV Package
5-Pin SOT-23
INA193, INA194, INA195 Top View**



**DBV Package
5-Pin SOT-23
INA196, INA197, INA198 Top View**



Pin Functions

NAME	PIN		TYPE	DESCRIPTION
	INA193, INA194, INA195	INA196, INA197, INA198		
	DBV	DBV		
GND	2	2	GND	Ground
OUT	1	1	O	Output voltage
V+	5	3	Analog	Power supply, 2.7 V to 18 V
V _{IN+}	3	4	I	Connect to supply side of shunt resistor
V _{IN-}	4	5	I	Connect to load side of shunt resistor

7 Specifications

7.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) ⁽¹⁾

	MIN	MAX	UNIT
Supply Voltage		18	V
Analog Inputs, V_{IN+} , V_{IN-}	-18	18	V
Differential (V_{IN+}) – (V_{IN-})	-18	18	V
Common-Mode ⁽²⁾	-16	80	V
Analog Output, $Out^{(2)}$	GND – 0.3	(V+) + 0.3	V
Input Current Into Any Pin ⁽²⁾		5	mA
Operating Temperature	-55	150	°C
Junction Temperature		150	°C
Storage temperature, T_{stg}	-65	150	°C

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) Input voltage at any pin may exceed the voltage shown if the current at that pin is limited to 5mA.

7.2 ESD Ratings

		VALUE	UNIT
$V_{(ESD)}$ Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins ⁽¹⁾	±4000	V
	Charged device model (CDM), per JEDEC specification JESD22-C101, all pins ⁽²⁾	±1000	

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

7.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
V_{CM}	Common-mode input voltage		12		V
$V+$	Operating supply voltage		12		V
T_A	Operating free-air temperature	-40		125	°C

7.4 Thermal Information

THERMAL METRIC ⁽¹⁾		INA19x	UNIT
		DBV (SOT-23)	
		5 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	221.7	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	144.7	
$R_{\theta JB}$	Junction-to-board thermal resistance	49.7	
Ψ_{JT}	Junction-to-top characterization parameter	26.1	
Ψ_{JB}	Junction-to-board characterization parameter	49.0	

- (1) For more information about traditional and new thermal metrics, see the *IC Package Thermal Metrics* application report, [SPRA953](#).

7.5 Electrical Characteristics

All specifications at $T_A = 25^\circ\text{C}$, $V_S = 12\text{ V}$, $V_{IN+} = 12\text{ V}$, and $V_{SENSE} = 100\text{ mV}$, unless otherwise noted.

PARAMETER		TEST CONDITIONS	T _A = 25°C			T _A = -40°C to +125°C			UNIT	
			MIN	TYP	MAX	MIN	TYP	MAX		
INPUT										
V _{SENSE}	Full-Scale Input Voltage	V _{SENSE} = V _{IN+} - V _{IN-}	0.15 (V _S - 0.2)/Gain			-16			V	
V _{CM}	Common-Mode Input Range		80			-16			V	
CMR	Common-Mode Rejection	V _{IN+} = -16 V to 80 V	80	94				dB		
	Common-Mode Rejection, Over Temperature	V _{IN+} = 12 V to 80 V				100	120	dB		
V _{OS}	Offset Voltage, RTI		±0.5		2		mV			
	Offset Voltage, RTI Over Temperature					0.5		3	mV	
dV _{OS} /dT	Offset Voltage, RTI vs Temperature					2.5		μV/°C		
PSR	Offset Voltage, RTI vs Power Supply	V _S = 2.7 V to 18 V, V _{IN+} = 18 V				5		100	μV/V	
I _B	Input Bias Current, V _{IN-} pin					±8		±16	μA	
OUTPUT (V_{SENSE} ≥ 20mV)										
G	Gain	INA193, INA196	20						V/V	
		INA194, INA197	50						V/V	
		INA195, INA198	100						V/V	
	Gain Error	V _{SENSE} = 20 mV to 100 mV, T _A = 25°C	±0.2%		±1%					
	Gain Error Over Temperature	V _{SENSE} = 20 mV to 100 mV						±2		
	Total Output Error ⁽¹⁾	V _{SENSE} = 100 mV	±0.75%		±2.2%					
	Total Output Error Over Temperature					±1%		±3%		
	Nonlinearity Error	V _{SENSE} = 20 mV to 100 mV	±0.002%		±0.1%					
R _O	Output Impedance		1.5						Ω	
	Maximum Capacitive Load	No Sustained Oscillation	10						nF	
Output ⁽²⁾	All Devices	-16 V ≤ V _{CM} < 0 V, V _{SENSE} < 20 mV	300						mV	
		V _S < V _{CM} ≤ 80 V, V _{SENSE} < 20 mV	300							
	INA193, INA196	0 V ≤ V _{CM} ≤ V _S , V _S = 5 V, V _{SENSE} < 20 mV				0.4		V		
	INA194, INA197					1		V		
INA195, INA198				2		V				
VOLTAGE OUTPUT⁽³⁾ (R_L = 100 kΩ to GND)										
	Swing to V+ Power-Supply Rail					(V+) - 0.1	(V+) - 0.2	V		
	Swing to GND ⁽⁴⁾					(V _{GND}) + 3	(V _{GND}) + 50	mV		
FREQUENCY RESPONSE										
BW	Bandwidth	INA193, INA196	C _{LOAD} = 5 pF	500						kHz
		INA194, INA197		300						kHz
		INA195, INA198		200						kHz

(1) Total output error includes effects of gain error and V_{OS}.

(2) For details on this region of operation, see the *Accuracy Variations as a Result of V_{SENSE} and Common-Mode Voltage* section.

(3) See Typical Characteristic curve *Output Swing vs Output Current*, Figure 7.

(4) Specified by design.

Electrical Characteristics (continued)

All specifications at $T_A = 25^\circ\text{C}$, $V_S = 12\text{ V}$, $V_{IN+} = 12\text{ V}$, and $V_{SENSE} = 100\text{ mV}$, unless otherwise noted.

PARAMETER	TEST CONDITIONS	$T_A = 25^\circ\text{C}$			$T_A = -40^\circ\text{C to } +125^\circ\text{C}$			UNIT
		MIN	TYP	MAX	MIN	TYP	MAX	
Phase Margin	$C_{LOAD} < 10\text{ nF}$		40					
SR	Slew Rate		1					V/ μs
t_S	Settling Time (1%)		2					μs
NOISE, RTI								
	Voltage Noise Density		40					nV/ $\sqrt{\text{Hz}}$
POWER SUPPLY								
V_S	Operating Range				2.7		18	V
I_Q	Quiescent Current	$V_{OUT} = 2\text{ V}$	700	900				μA
	Quiescent Current Over Temperature	$V_{SENSE} = 0\text{ mV}$				370	950	μA
TEMPERATURE RANGE								
	Specified Temperature Range		-40	125				$^\circ\text{C}$
	Operating Temperature Range		-55	150				$^\circ\text{C}$
	Storage Temperature Range		-65	150				$^\circ\text{C}$
θ_{JA}	Thermal Resistance, SOT23		200					$^\circ\text{C/W}$

7.6 Typical Characteristics

All specifications at $T_A = 25^\circ\text{C}$, $V_S = 12\text{ V}$, and $V_{IN+} = 12\text{ V}$, and $V_{SENSE} = 100\text{ mV}$, unless otherwise noted.

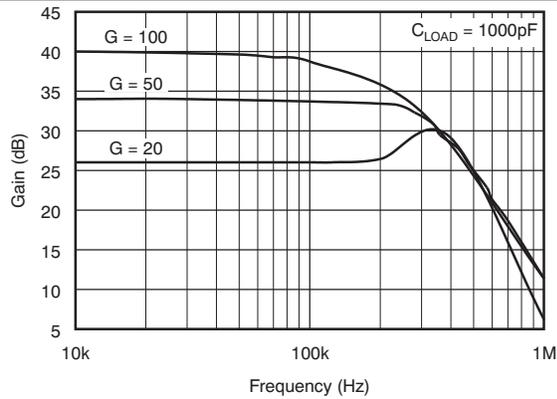


Figure 1. Gain vs Frequency

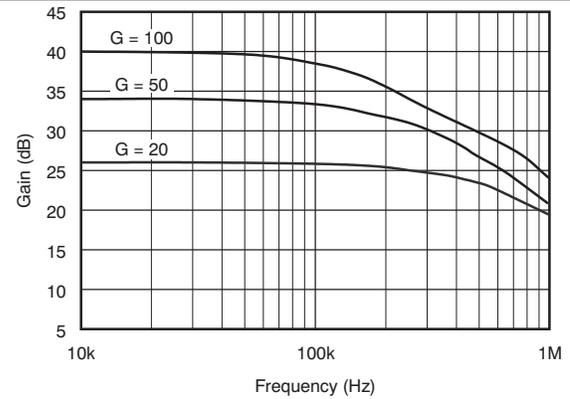


Figure 2. Gain vs Frequency

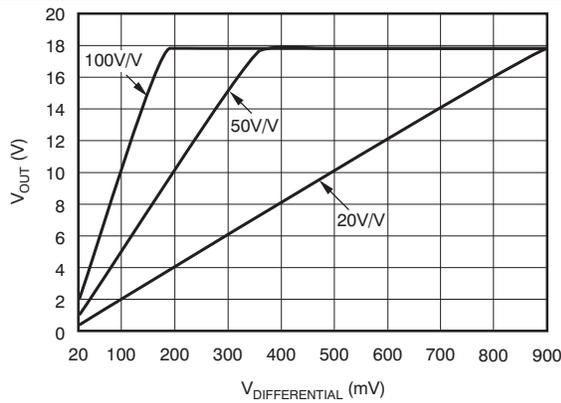


Figure 3. Gain Plot

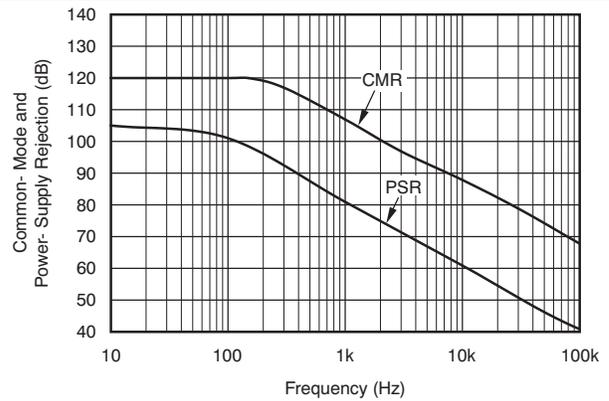


Figure 4. Common-Mode and Power-Supply Rejection vs Frequency

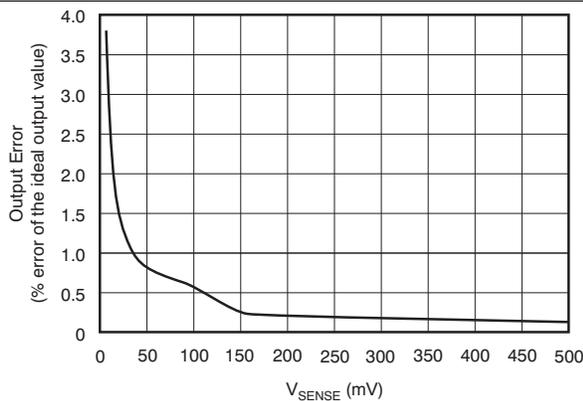


Figure 5. Output Error vs V_{SENSE}

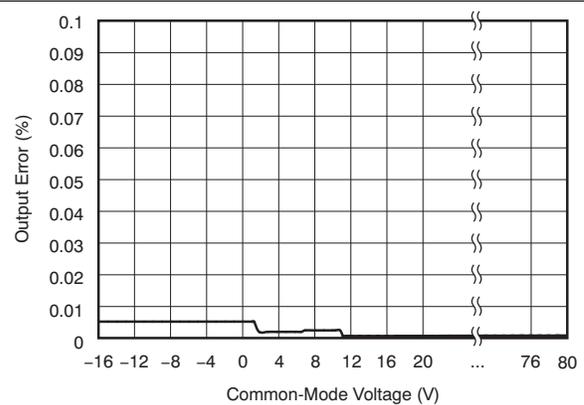
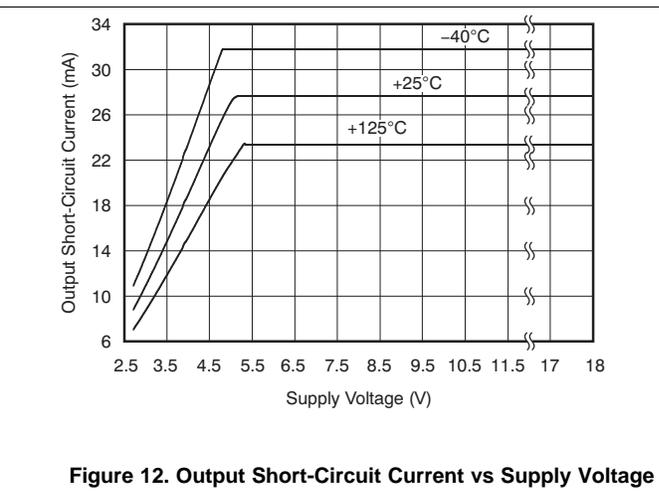
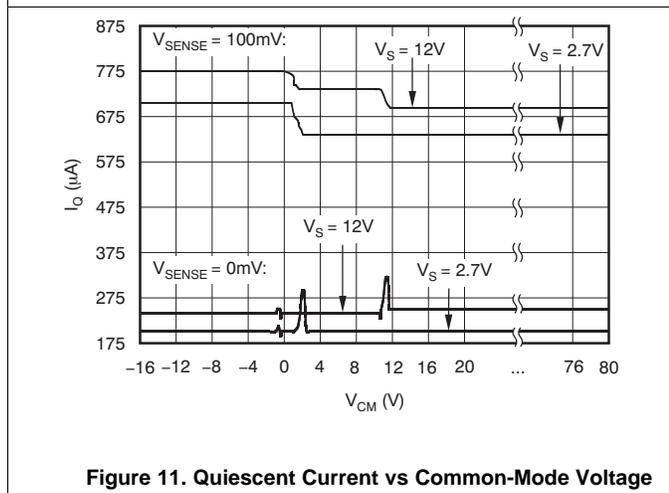
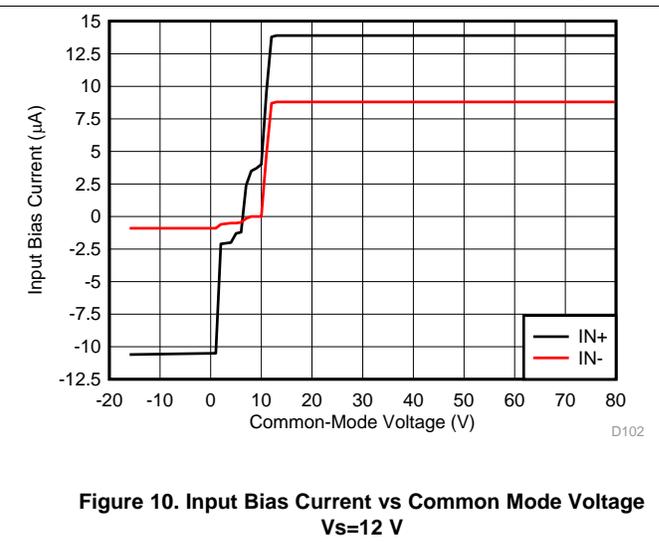
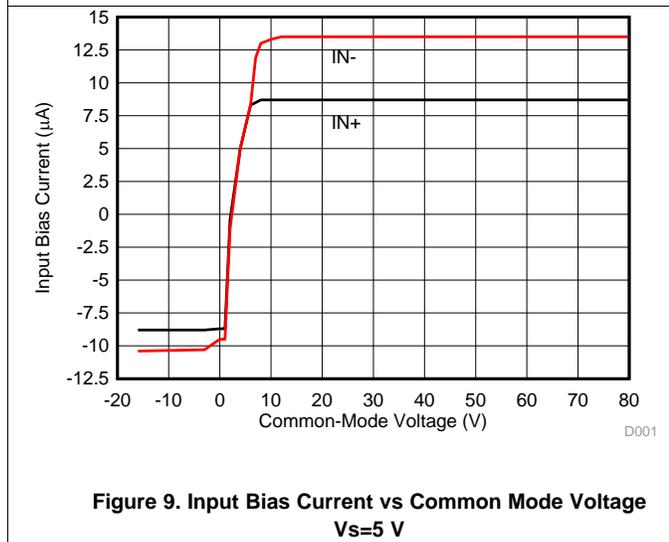
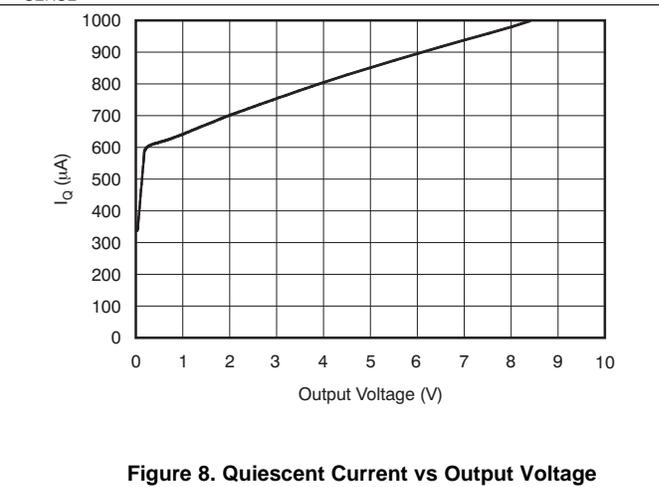
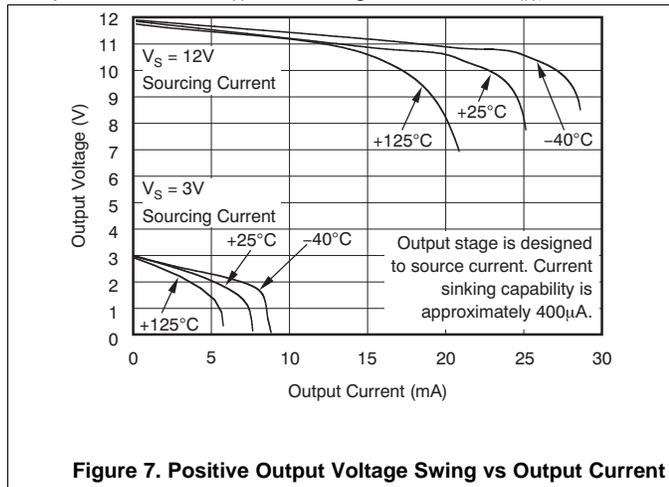


Figure 6. Output Error vs Common-Mode Voltage

Typical Characteristics (continued)

All specifications at $T_A = 25^\circ\text{C}$, $V_S = 12\text{ V}$, and $V_{IN+} = 12\text{ V}$, and $V_{SENSE} = 100\text{ mV}$, unless otherwise noted.



Typical Characteristics (continued)

All specifications at $T_A = 25^\circ\text{C}$, $V_S = 12\text{ V}$, and $V_{IN+} = 12\text{ V}$, and $V_{SENSE} = 100\text{ mV}$, unless otherwise noted.

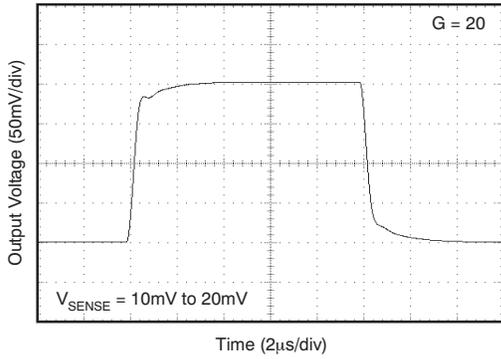


Figure 13. Step Response

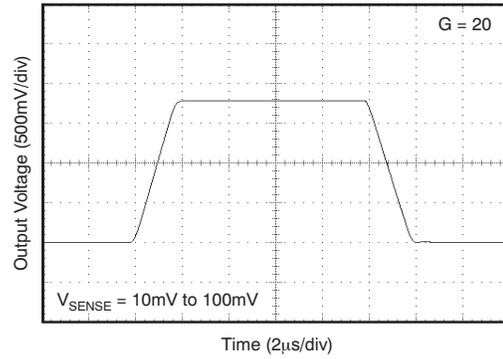


Figure 14. Step Response

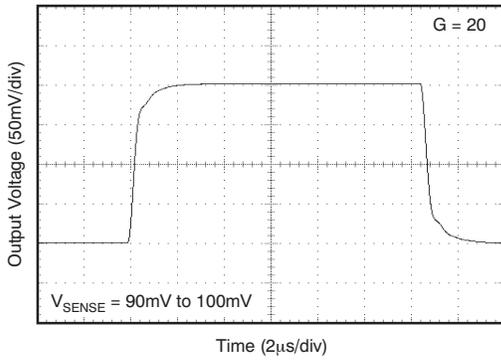


Figure 15. Step Response

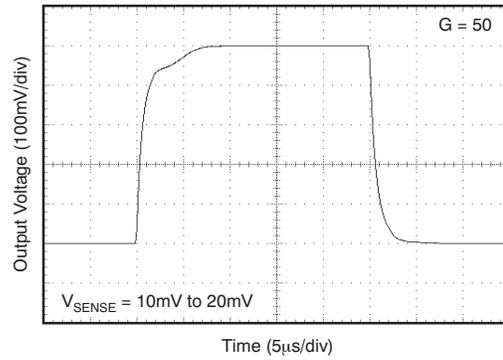


Figure 16. Step Response

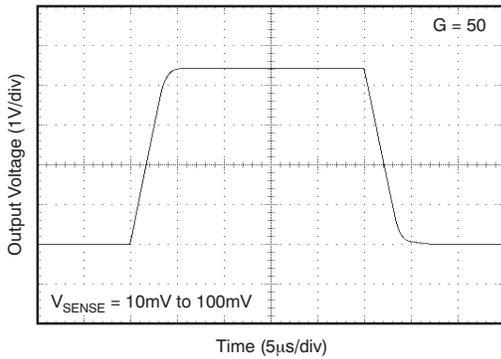


Figure 17. Step Response

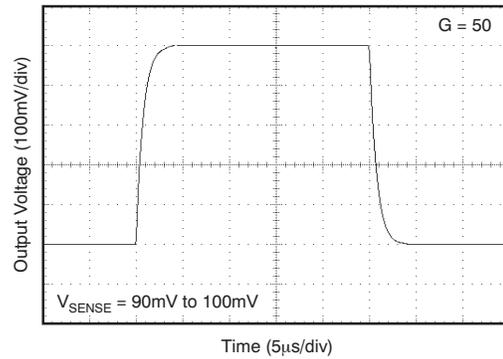


Figure 18. Step Response

Typical Characteristics (continued)

All specifications at $T_A = 25^\circ\text{C}$, $V_S = 12\text{ V}$, and $V_{IN+} = 12\text{ V}$, and $V_{SENSE} = 100\text{ mV}$, unless otherwise noted.

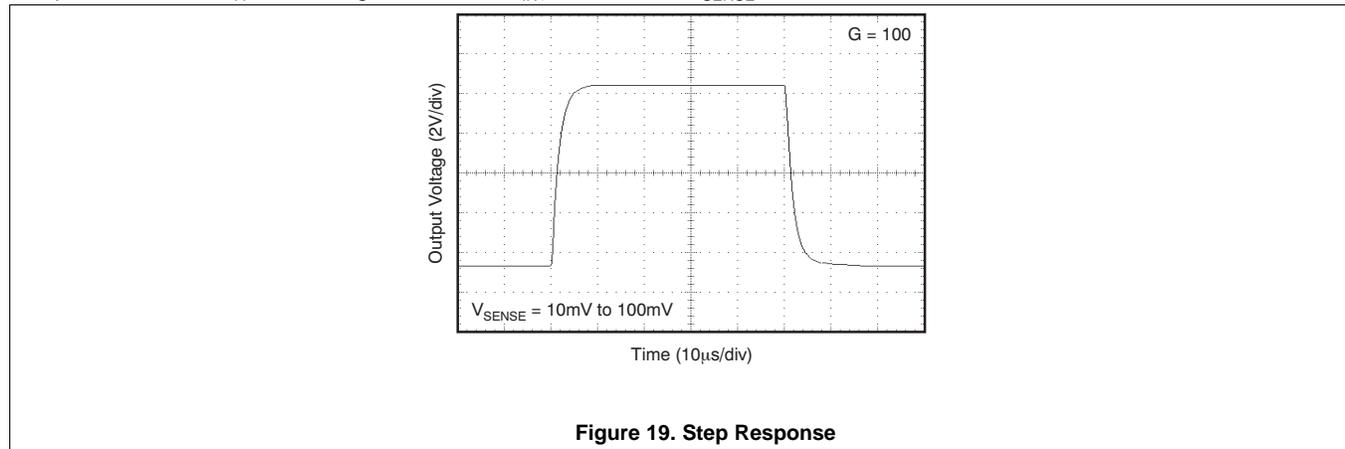


Figure 19. Step Response

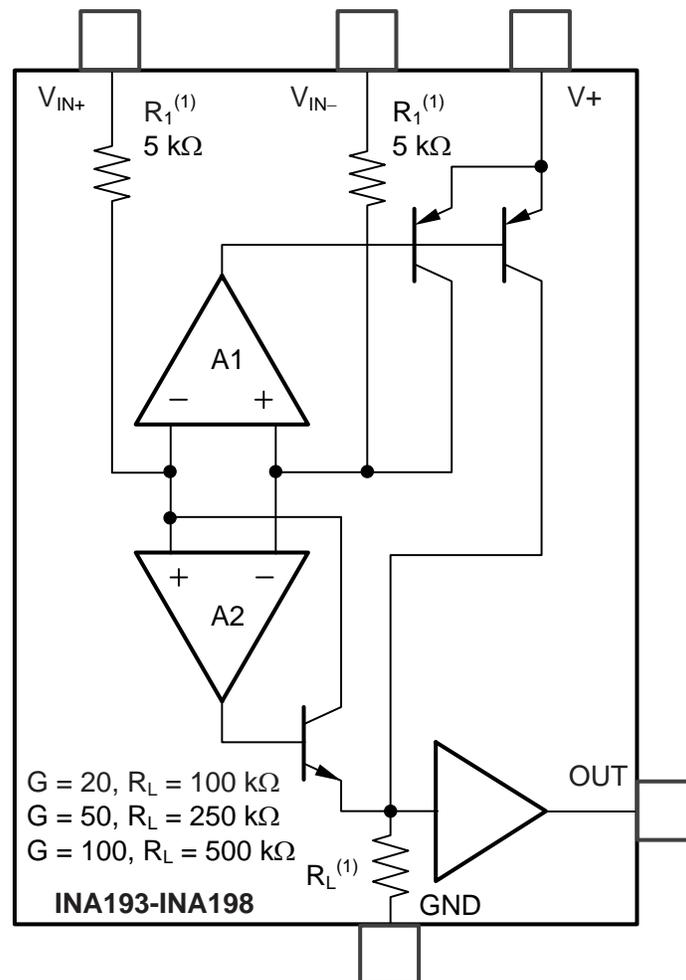
8 Detailed Description

8.1 Overview

The INA193–INA198 family of current shunt monitors with voltage output can sense drops across shunts at common-mode voltages from -16 V to $+80\text{ V}$, independent of the INA19x supply voltage. They are available with three output voltage scales: 20 V/V, 50 V/V, and 100 V/V. The 500-kHz bandwidth simplifies use in current control loops. The INA193–INA195 devices provide identical functions but alternative pin configurations to the INA196–INA198, respectively.

The INA193–INA198 devices operate from a single $+2.7\text{-V}$ to $+18\text{-V}$ supply, drawing a maximum of $900\text{ }\mu\text{A}$ of supply current. They are specified over the extended operating temperature range (-40°C to $+125^\circ\text{C}$), and are offered in a space-saving SOT-23 package.

8.2 Functional Block Diagram



8.3 Feature Description

8.3.1 Basic Connection

Figure 20 shows the basic connection of the INA193-INA198. To minimize any resistance in series with the shunt resistor, connect the input pins, V_{IN+} and V_{IN-} , as closely as possible to the shunt resistor.

Power-supply bypass capacitors are required for stability. Applications with noisy or high impedance power supplies may require additional decoupling capacitors to reject power-supply noise. Connect bypass capacitors close to the device pins.

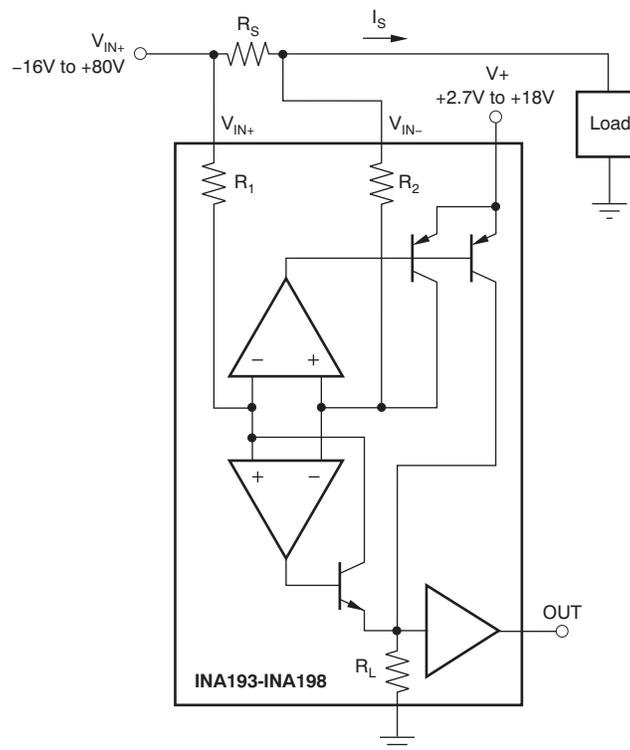


Figure 20. INA193-INA198 Basic Connection

8.3.2 Selecting R_S

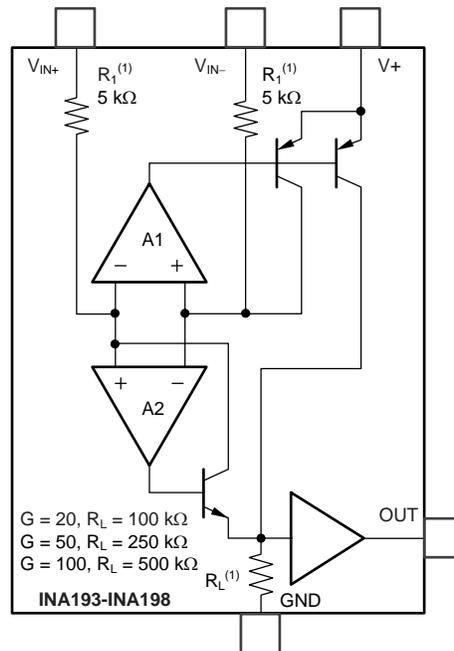
The value chosen for the shunt resistor, R_S , depends on the application and is a compromise between small-signal accuracy and maximum permissible voltage loss in the measurement line. High values of R_S provide better accuracy at lower currents by minimizing the effects of offset, while low values of R_S minimize voltage loss in the supply line. For most applications, best performance is attained with an R_S value that provides a full-scale shunt voltage range of 50 mV to 100 mV. Maximum input voltage for accurate measurements is 500 mV.

8.3.3 Inside the INA193-INA198

The INA193-INA198 devices use a new, unique internal circuit topology that provides common-mode range extending from -16 to 80 V while operating from a single power supply. The common-mode rejection in a classic instrumentation amplifier approach is limited by the requirement for accurate resistor matching. By converting the induced input voltage to a current, the INA193-INA198 devices provide common-mode rejection that is no longer a function of closely matched resistor values, providing the enhanced performance necessary for such a wide common-mode range. A simplified diagram (shown in Figure 21) shows the basic circuit function. When the common-mode voltage is positive, amplifier A2 is active.

Feature Description (continued)

The differential input voltage, $(V_{IN+}) - (V_{IN-})$ applied across R_S , is converted to a current through a resistor. This current is converted back to a voltage through R_L , and then amplified by the output buffer amplifier. When the common-mode voltage is negative, amplifier A1 is active. The differential input voltage, $(V_{IN+}) - (V_{IN-})$ applied across R_S , is converted to a current through a resistor. This current is sourced from a precision current mirror whose output is directed into R_L converting the signal back into a voltage and amplified by the output buffer amplifier. Patent-pending circuit architecture ensures smooth device operation, even during the transition period where both amplifiers A1 and A2 are active.



(1) Nominal resistor values are shown. $\pm 15\%$ variation is possible. Resistor ratios are matched to $\pm 1\%$.

Figure 21. INA193-INA198 Simplified Circuit Diagram

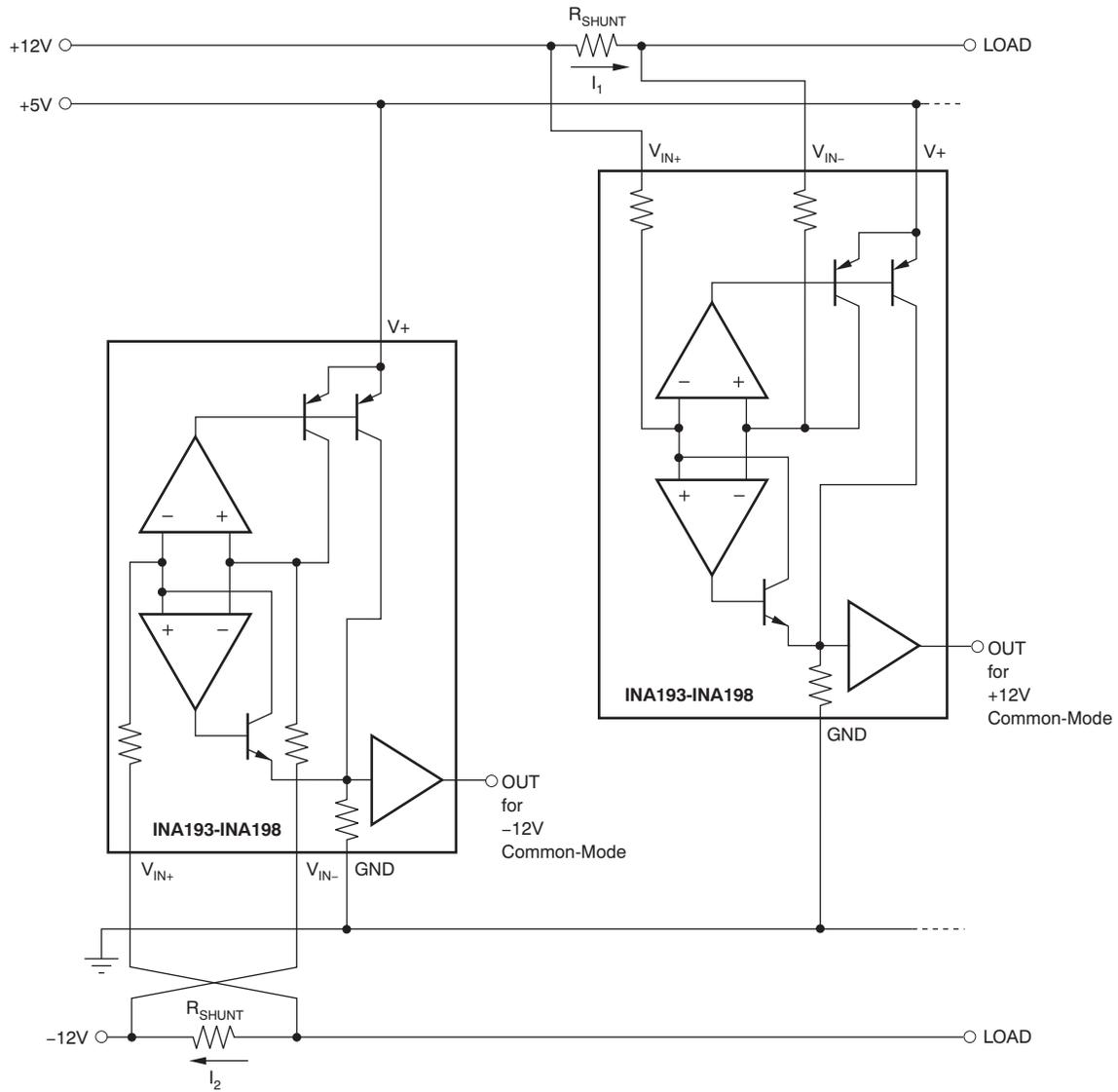


Figure 22. Monitor Bipolar Output Power-Supply Current

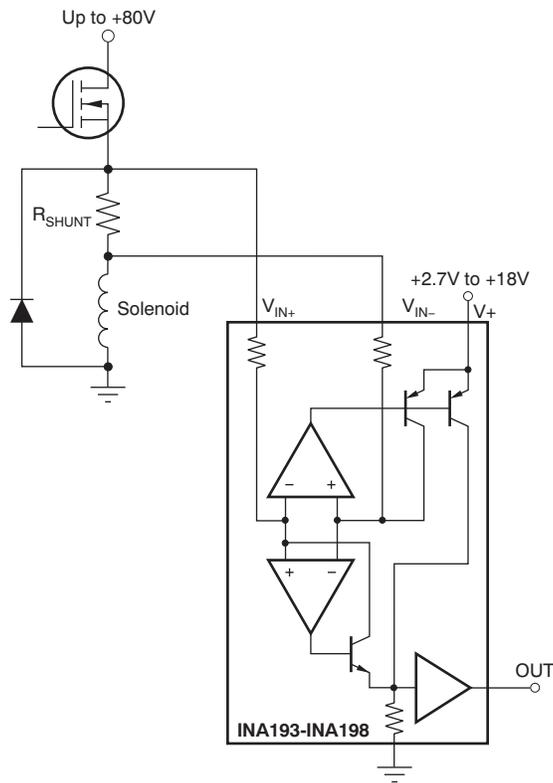
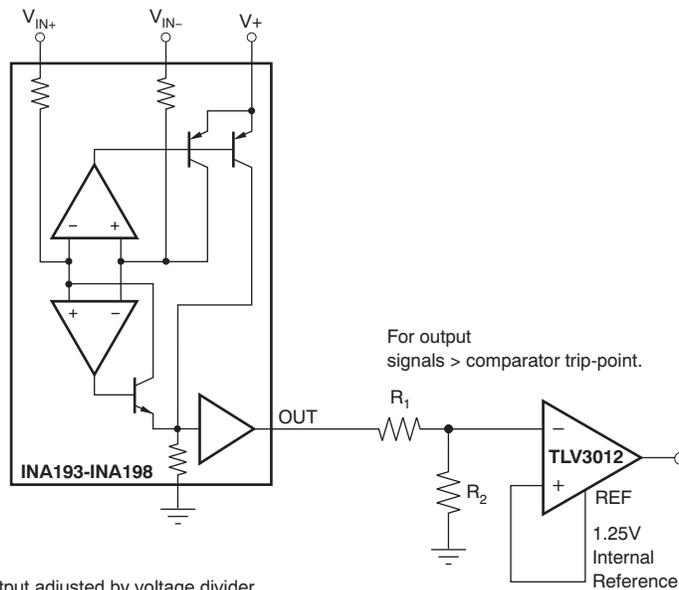
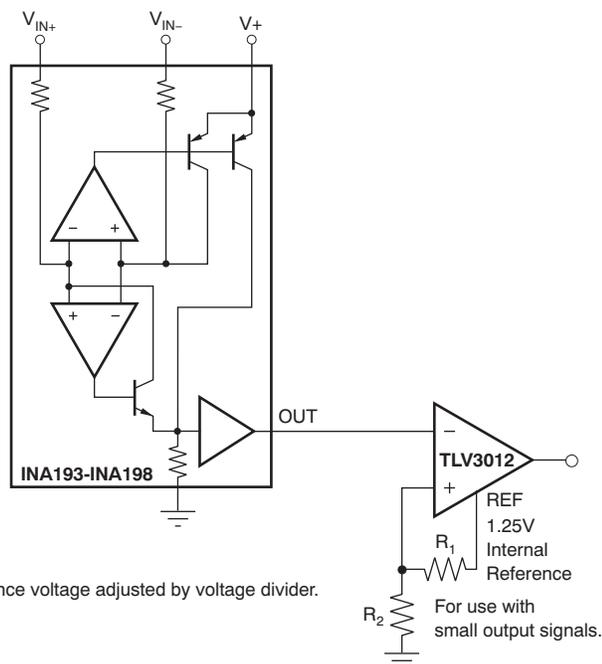


Figure 23. Inductive Current Monitor Including Flyback



(a) INA193-INA198 output adjusted by voltage divider.



(b) Comparator reference voltage adjusted by voltage divider.

Figure 24. INA193-INA198 with Comparator

8.4 Device Functional Modes

8.4.1 Input Filtering

An obvious and straightforward location for filtering is at the output of the INA193-INA198 devices; however, this location negates the advantage of the low output impedance of the internal buffer. The only other option for filtering is at the input pins of the INA193-INA198 devices, which is complicated by the internal 5-k Ω + 30% input impedance; this is illustrated in [Figure 25](#). Using the lowest possible resistor values minimizes both the initial shift in gain and effects of tolerance. The effect on initial gain is given by [Equation 1](#):

Device Functional Modes (continued)

$$\text{GainError\%} = 100 - \left(\frac{5\text{k}\Omega}{5\text{k}\Omega + R_{\text{FILT}}} \right) \times 100 \quad (1)$$

Total effect on gain error can be calculated by replacing the 5-k Ω term with 5 k Ω – 30%, (or 3.5 k Ω) or 5 k Ω + 30% (or 6.5 k Ω). The tolerance extremes of R_{FILT} can also be inserted into the equation. If a pair of 100- Ω 1% resistors are used on the inputs, the initial gain error will be approximately 2%. Worst-case tolerance conditions will always occur at the lower excursion of the internal 5-k Ω resistor (3.5 k Ω), and the higher excursion of R_{FILT} – 3% in this case.

Note that the specified accuracy of the INA193-INA198 devices must then be combined in addition to these tolerances. While this discussion treated accuracy worst-case conditions by combining the extremes of the resistor values, it is appropriate to use geometric mean or root sum square calculations to total the effects of accuracy variations.

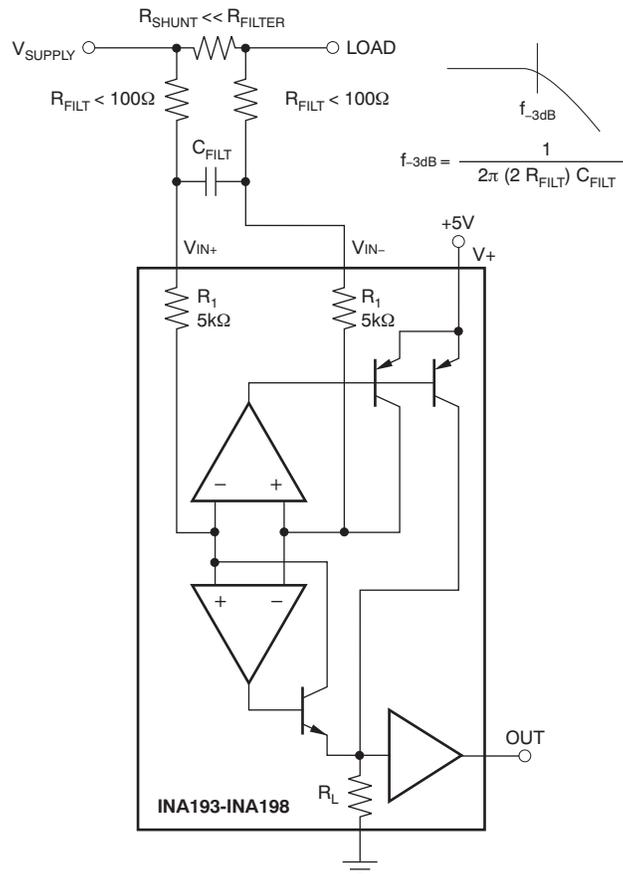


Figure 25. Input Filter (Gain Error – 1.5% To –2.2%)

8.4.2 Accuracy Variations as a Result of V_{SENSE} and Common-Mode Voltage

The accuracy of the INA193–INA198 current shunt monitors is a function of two main variables: V_{SENSE} ($V_{\text{IN}+} - V_{\text{IN}-}$) and common-mode voltage, V_{CM} , relative to the supply voltage, V_{S} . V_{CM} is expressed as $(V_{\text{IN}+} + V_{\text{IN}-})/2$; however, in practice, V_{CM} is seen as the voltage at $V_{\text{IN}+}$ because the voltage drop across V_{SENSE} is usually small.

This section addresses the accuracy of these specific operating regions:

- Normal Case 1: $V_{\text{SENSE}} \geq 20\text{mV}$, $V_{\text{CM}} \geq V_{\text{S}}$
- Normal Case 2: $V_{\text{SENSE}} \geq 20\text{mV}$, $V_{\text{CM}} < V_{\text{S}}$
- Low V_{SENSE} Case 1: $V_{\text{SENSE}} < 20\text{mV}$, $-16\text{V} \leq V_{\text{CM}} < 0$
- Low V_{SENSE} Case 2: $V_{\text{SENSE}} < 20\text{mV}$, $0\text{V} \leq V_{\text{CM}} \leq V_{\text{S}}$

Device Functional Modes (continued)

Low V_{SENSE} Case 3: $V_{SENSE} < 20\text{mV}$, $V_S < V_{CM} \leq 80\text{V}$

8.4.2.1 Normal Case 1: $V_{SENSE} \geq 20\text{mV}$, $V_{CM} \geq V_S$

This region of operation provides the highest accuracy. Here, the input offset voltage is characterized and measured using a two-step method. First, the gain is determined by [Equation 2](#).

$$G = \frac{V_{OUT1} - V_{OUT2}}{100\text{mV} - 20\text{mV}}$$

where:

V_{OUT1} = Output Voltage with $V_{SENSE} = 100\text{mV}$

V_{OUT2} = Output Voltage with $V_{SENSE} = 20\text{mV}$

(2)

Then the offset voltage is measured at $V_{SENSE} = 100\text{mV}$ and referred to the input (RTI) of the current shunt monitor, as shown in [Equation 3](#).

$$V_{OSRTI} \text{ (Referred-To-Input)} = \left[\frac{V_{OUT1}}{G} \right] - 100\text{mV}$$

(3)

In the [Typical Characteristics](#), the *Output Error vs Common-Mode Voltage* curve ([Figure 6](#)) shows the highest accuracy for this region of operation. In this plot, $V_S = 12\text{V}$; for $V_{CM} \geq 12\text{V}$, the output error is at its minimum. This case is also used to create the $V_{SENSE} \geq 20\text{-mV}$ output specifications in the [Electrical Characteristics](#) table.

8.4.2.2 Normal Case 2: $V_{SENSE} \geq 20\text{mV}$, $V_{CM} < V_S$

This region of operation has slightly less accuracy than Normal Case 1 as a result of the common-mode operating area in which the part functions, as seen in the *Output Error vs Common-Mode Voltage* curve ([Figure 6](#)). As noted, for this graph $V_S = 12\text{V}$; for $V_{CM} < 12\text{V}$, the Output Error increases as V_{CM} becomes less than 12V , with a typical maximum error of 0.005% at the most negative $V_{CM} = -16\text{V}$.

Device Functional Modes (continued)

8.4.2.3 Low V_{SENSE} Case 1: $V_{SENSE} < 20\text{mV}$, $-16\text{V} \leq V_{CM} < 0$; and Low V_{SENSE} Case 3: $V_{SENSE} < 20\text{mV}$, $V_S < V_{CM} \leq 80\text{V}$

Although the INA193–INA198 family of devices are not designed for accurate operation in either of these regions, some applications are exposed to these conditions; for example, when monitoring power supplies that are switched on and off while V_S is still applied to the INA193–INA198 devices. It is important to know what the behavior of the devices will be in these regions.

As V_{SENSE} approaches 0 mV, in these V_{CM} regions, the device output accuracy degrades. A larger-than-normal offset can appear at the current shunt monitor output with a typical maximum value of $V_{OUT} = 300\text{ mV}$ for $V_{SENSE} = 0\text{ mV}$. As V_{SENSE} approaches 20 mV, V_{OUT} returns to the expected output value with accuracy as specified in the [Electrical Characteristics](#). Figure 26 illustrates this effect using the INA195 and INA198 devices (Gain = 100).

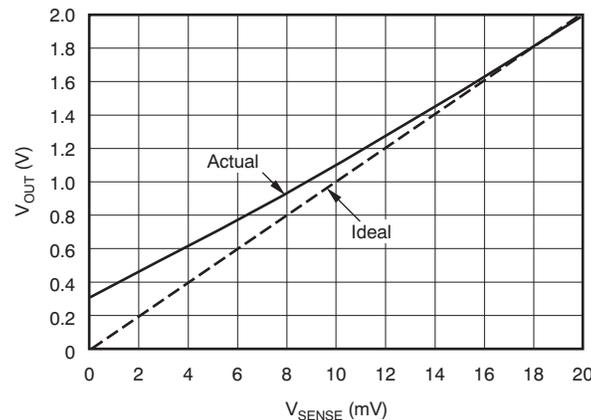
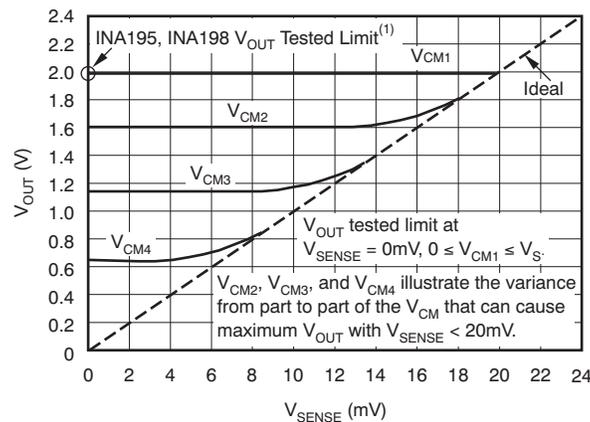


Figure 26. Example for Low V_{SENSE} Cases 1 and 3 (INA195, INA198: Gain = 100)

8.4.2.4 Low V_{SENSE} Case 2: $V_{SENSE} < 20\text{ mV}$, $0\text{ V} \leq V_{CM} \leq V_S$

This region of operation is the least accurate for the INA193–INA198 family of devices. To achieve the wide input common-mode voltage range, these devices use two op amp front ends in parallel. One op amp front end operates in the positive input common-mode voltage range, and the other in the negative input region. For this case, neither of these two internal amplifiers dominates and overall loop gain is very low. Within this region, V_{OUT} approaches voltages close to linear operation levels for Normal Case 2. This deviation from linear operation becomes greatest the closer V_{SENSE} approaches 0 V. Within this region, as V_{SENSE} approaches 20 mV, device operation is closer to that described by Normal Case 2. Figure 27 illustrates this behavior for the INA195 device. The V_{OUT} maximum peak for this case is tested by maintaining a constant V_S , setting $V_{SENSE} = 0\text{ mV}$ and sweeping V_{CM} from 0 V to V_S . The exact V_{CM} at which V_{OUT} peaks during this test varies from part to part, but the V_{OUT} maximum peak is tested to be less than the specified V_{OUT} Tested Limit.

Device Functional Modes (continued)



(1) INA193, INA196 V_{OUT} Tested Limit = 0.4V. INA194, INA197 V_{OUT} Tested Limit = 1V.

Figure 27. Example for Low V_{SENSE} Case 2 (INA195, INA198: Gain = 100)

8.4.3 Shutdown

Because the INA193-INA198 devices consume a quiescent current less than 1 mA, they can be powered by either the output of logic gates or by transistor switches to supply power. Use a totem-pole output buffer or gate that can provide sufficient drive along with 0.1- μ F bypass capacitor, preferably ceramic with good high-frequency characteristics. This gate should have a supply voltage of 3 V or greater because the INA193-INA198 devices require a minimum supply greater than 2.7 V. In addition to eliminating quiescent current, this gate also turns off the 10- μ A bias current present at each of the inputs. An example shutdown circuit is shown in Figure 28.

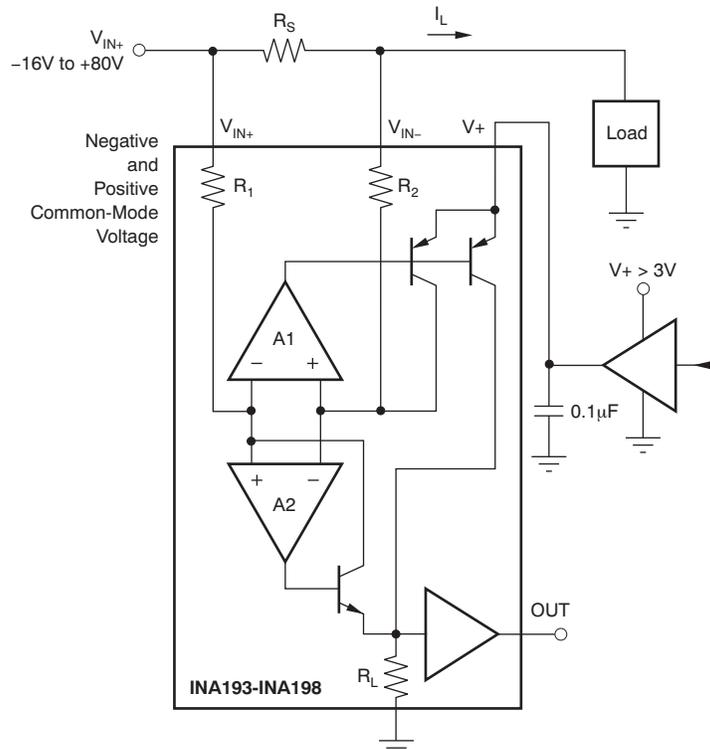


Figure 28. INA193-INA198 Example Shutdown Circuit

Device Functional Modes (continued)

8.4.4 Transient Protection

The -16-V to $+80\text{-V}$ common-mode range of the INA193-INA198 devices is ideal for withstanding automotive fault conditions ranging from 12-V battery reversal up to 80-V transients, since no additional protective components are needed up to those levels. In the event that the INA193-INA198 devices are exposed to transients on the inputs in excess of its ratings, then external transient absorption with semiconductor transient absorbers (zeners or Transzorbs) will be necessary. Use of MOVs or VDRs is not recommended except when they are used in addition to a semiconductor transient absorber. Select the transient absorber such that it will never allow the INA193-INA198 devices to be exposed to transients greater than $+80\text{ V}$ (that is, allow for transient absorber tolerance, as well as additional voltage due to transient absorber dynamic impedance). Despite the use of internal zener-type ESD protection, the INA193-INA198 devices do not lend themselves to using external resistors in series with the inputs because the internal gain resistors can vary up to $\pm 30\%$. (If gain accuracy is not important, then resistors can be added in series with the INA193-INA198 inputs with two equal resistors on each input.)

8.4.5 Output Voltage Range

The output of the INA193-INA198 devices are accurate within the output voltage swing range set by the power-supply pin, $V+$. This is best illustrated when using the INA195 or INA198 devices (which are both versions using a gain of 100), where a 100-mV full-scale input from the shunt resistor requires an output voltage swing of $+10\text{ V}$, and a power-supply voltage sufficient to achieve $+10\text{ V}$ on the output.

9 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

9.1 Application Information

The INA193-INA198 devices measure the voltage developed across a current-sensing resistor when current passes through it. The ability to have shunt common-mode voltages from -16-V to $+80\text{-V}$ drive and control the output signal with V_s offers multiple configurations, as discussed throughout this section.

9.2 Typical Application

The device is a unidirectional, current-sense amplifier capable of measuring currents through a resistive shunt with shunt common-mode voltages from -16 V to 80 V . Two devices can be configured for bidirectional monitoring and is common in applications that include charging and discharging operations where the current flow-through resistor can change directions.

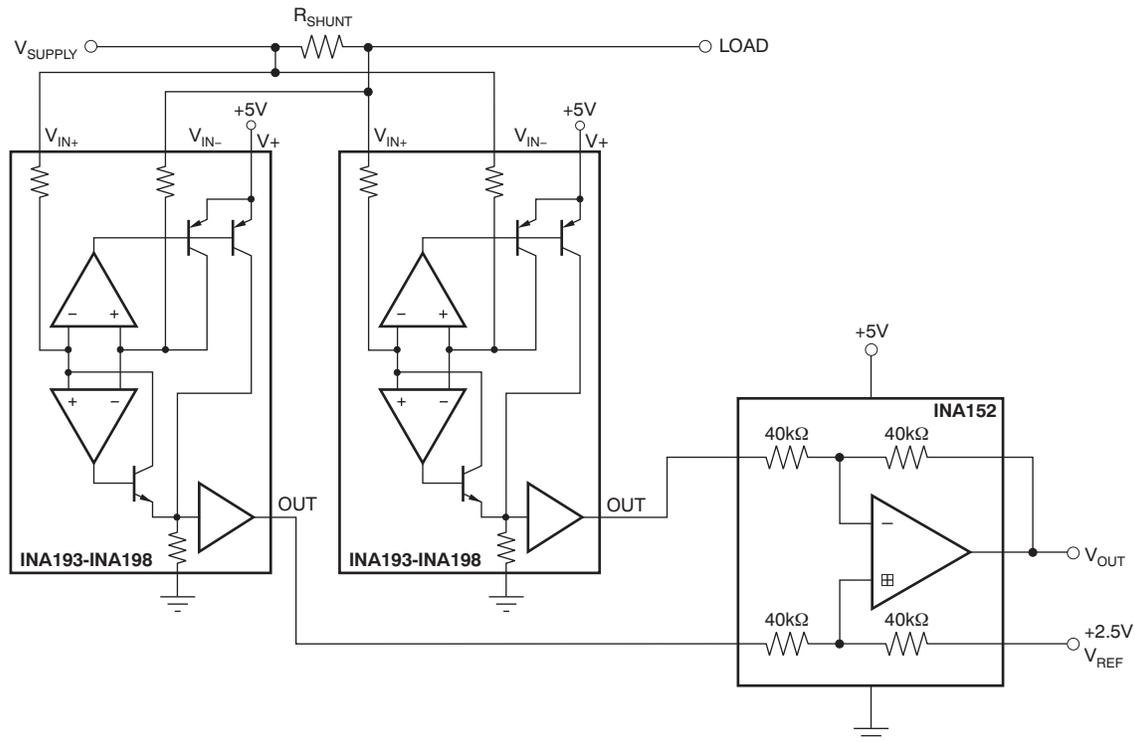


Figure 29. Bi-Directional Current Monitoring

9.2.1 Design Requirements

V_{supply} is set to 12 V , V_{ref} at 2.5 V and a $10\text{-m}\Omega$ shunt. The accuracy of the current will typically be less than 0.5% for current greater than $\pm 2\text{ A}$. For current lower than $\pm 2\text{ A}$, the accuracy will vary; use the [Device Functional Modes](#) section for accuracy considerations.

Typical Application (continued)

9.2.2 Detailed Design Procedure

The ability to measure this current flowing in both directions is enabled by adding a unity gain amplifier with a V_{REF} , as shown in Figure 29. The output then responds by increasing above V_{REF} for positive differential signals (relative to the IN – pin) and responds by decreasing below V_{REF} for negative differential signals. This reference voltage applied to the REF pin can be set anywhere between 0 V to V_+ . For bidirectional applications, V_{REF} is typically set at mid-scale for equal signal range in both current directions. In some cases, however, V_{REF} is set at a voltage other than mid-scale when the bidirectional current and corresponding output signal do not need to be symmetrical.

9.2.3 Application Curve

An example output response of a bidirectional configuration is shown in Figure 30. With the REF pin connected to a reference voltage, 2.5 V in this case, the output voltage is biased upwards by this reference level. The output rises above the reference voltage for positive differential input signals and falls below the reference voltage for negative differential input signals.

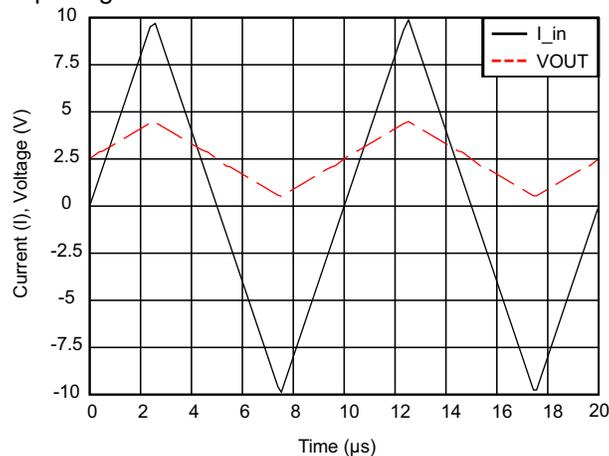


Figure 30. Output Voltage vs Shunt Input Current

10 Power Supply Recommendations

The input circuitry of the INA193-INA198 devices can accurately measure beyond its power-supply voltage, V_+ . For example, the V_+ power supply can be 5 V, whereas the load power-supply voltage is up to 80 V. The output voltage range of the OUT terminal, however, is limited by the voltages on the power-supply pin.

11 Layout

11.1 Layout Guidelines

11.1.1 RFI and EMI

Attention to good layout practices is always recommended. Keep traces short and, when possible, use a printed circuit board (PCB) ground plane with surface-mount components placed as close to the device pins as possible. Small ceramic capacitors placed directly across amplifier inputs can reduce RFI/EMI sensitivity. PCB layout should locate the amplifier as far away as possible from RFI sources. Sources can include other components in the same system as the amplifier itself, such as inductors (particularly switched inductors handling a lot of current and at high frequencies). RFI can generally be identified as a variation in offset voltage or DC signal levels with changes in the interfering RF signal. If the amplifier cannot be located away from sources of radiation, shielding may be needed. Twisting wire input leads makes them more resistant to RF fields. The difference in input pin location of the INA193-INA195 devices versus the INA196-INA198 devices may provide different EMI performance.

11.2 Layout Example

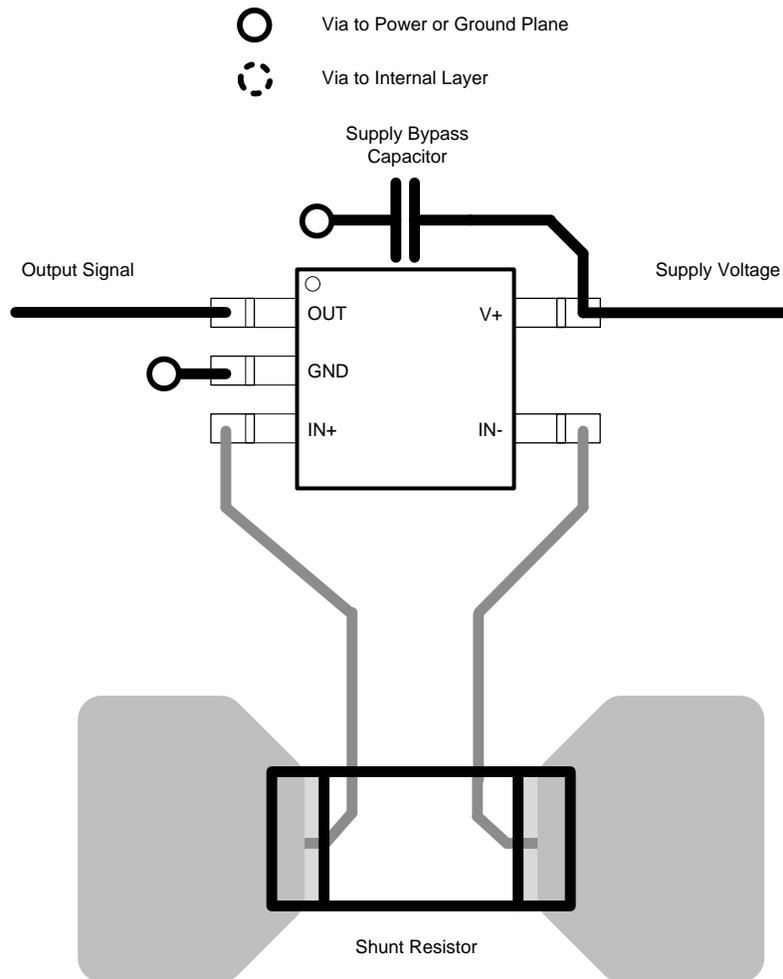


Figure 31. Recommended Layout

12 器件和文档支持

12.1 相关链接

下面的表格列出了快速访问链接。范围包括技术文档、支持和社区资源、工具和软件，以及样片或购买的快速访问。

表 1. 相关链接

器件	产品文件夹	样片与购买	技术文档	工具与软件	支持与社区
INA193	请单击此处				
INA194	请单击此处				
INA195	请单击此处				
INA196	请单击此处				
INA197	请单击此处				
INA198	请单击此处				

12.2 商标

All trademarks are the property of their respective owners.

12.3 静电放电警告



这些装置包含有限的内置 ESD 保护。存储或装卸时，应将导线一起截短或将装置放置于导电泡棉中，以防止 MOS 门极遭受静电损伤。

12.4 Glossary

[SLYZ022](#) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

13 机械、封装和可订购信息

以下页中包括机械、封装和可订购信息。这些信息是针对指定器件可提供的最新数据。这些数据会在无通知且不对本文档进行修订的情况下发生改变。欲获得该数据表的浏览器版本，请查阅左侧的导航栏。

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
INA193AIDBVR	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU SN	Level-2-260C-1 YEAR	-40 to 125	BJJ
INA193AIDBVR.A	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	BJJ
INA193AIDBVR1G4	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	BJJ
INA193AIDBVR1G4.A	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	BJJ
INA193AIDBVT	Active	Production	SOT-23 (DBV) 5	250 SMALL T&R	Yes	NIPDAU SN	Level-2-260C-1 YEAR	-40 to 125	BJJ
INA193AIDBVT.A	Active	Production	SOT-23 (DBV) 5	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	BJJ
INA194AIDBVR	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU SN	Level-2-260C-1 YEAR	-40 to 125	BJI
INA194AIDBVR.A	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	BJI
INA194AIDBVR1G4	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	BJI
INA194AIDBVR1G4.A	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	BJI
INA194AIDBVT	Active	Production	SOT-23 (DBV) 5	250 SMALL T&R	Yes	NIPDAU SN	Level-2-260C-1 YEAR	-40 to 125	BJI
INA194AIDBVT.A	Active	Production	SOT-23 (DBV) 5	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	BJI
INA195AIDBVR	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU SN	Level-2-260C-1 YEAR	-40 to 125	BJK
INA195AIDBVR.A	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	BJK
INA195AIDBVRG4	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	BJK
INA195AIDBVRG4.A	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	BJK
INA195AIDBVT	Active	Production	SOT-23 (DBV) 5	250 SMALL T&R	Yes	NIPDAU SN	Level-2-260C-1 YEAR	-40 to 125	BJK
INA195AIDBVT.A	Active	Production	SOT-23 (DBV) 5	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	BJK
INA196AIDBVR	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	BJE
INA196AIDBVR.A	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	BJE
INA196AIDBVR1G4	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	BJE
INA196AIDBVR1G4.A	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	BJE
INA196AIDBVT	Active	Production	SOT-23 (DBV) 5	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	BJE
INA196AIDBVT.A	Active	Production	SOT-23 (DBV) 5	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	BJE
INA197AIDBVR	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	BJH
INA197AIDBVR.A	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	BJH
INA197AIDBVR1G4	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	BJH
INA197AIDBVR1G4.A	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	BJH
INA197AIDBVT	Active	Production	SOT-23 (DBV) 5	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	BJH

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
INA197AIDBVT.A	Active	Production	SOT-23 (DBV) 5	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	BJH
INA198AIDBVR	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	BJL
INA198AIDBVR.A	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	BJL
INA198AIDBVRG4	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	BJL
INA198AIDBVRG4.A	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	BJL
INA198AIDBVT	Active	Production	SOT-23 (DBV) 5	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	BJL
INA198AIDBVT.A	Active	Production	SOT-23 (DBV) 5	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	BJL

(1) **Status:** For more details on status, see our [product life cycle](#).

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

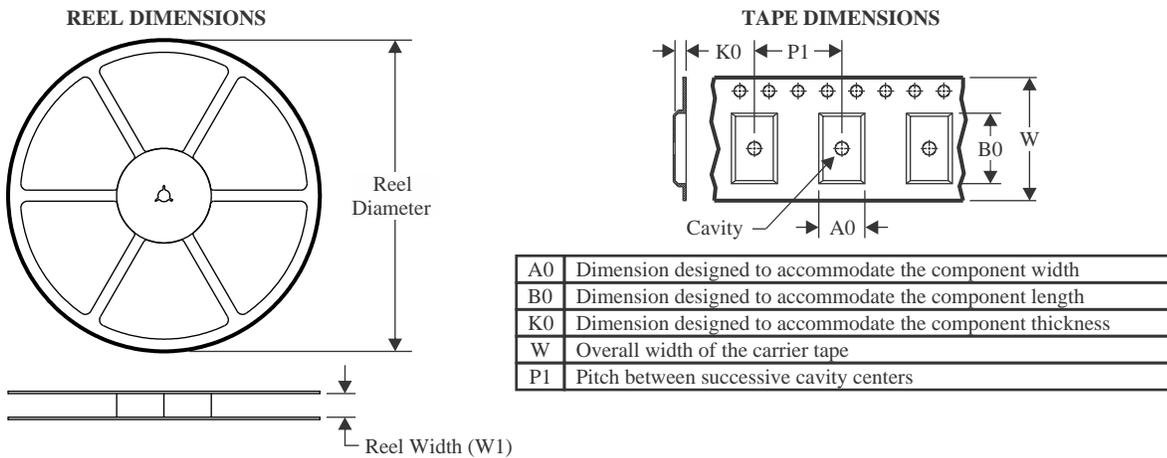
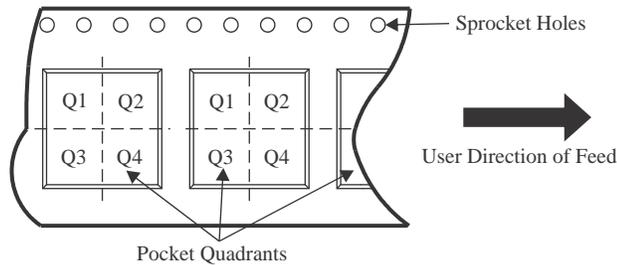
(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "-" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

TAPE AND REEL INFORMATION

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
INA193AIDBVR	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
INA193AIDBVR1G4	SOT-23	DBV	5	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
INA193AIDBVT	SOT-23	DBV	5	250	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
INA194AIDBVR	SOT-23	DBV	5	3000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
INA194AIDBVR1G4	SOT-23	DBV	5	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
INA194AIDBVT	SOT-23	DBV	5	250	178.0	9.0	3.3	3.2	1.4	4.0	8.0	Q3
INA194AIDBVT	SOT-23	DBV	5	250	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
INA195AIDBVR	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
INA195AIDBVRG4	SOT-23	DBV	5	3000	178.0	9.0	3.3	3.2	1.4	4.0	8.0	Q3
INA195AIDBVT	SOT-23	DBV	5	250	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
INA196AIDBVR	SOT-23	DBV	5	3000	178.0	9.0	3.3	3.2	1.4	4.0	8.0	Q3
INA196AIDBVR1G4	SOT-23	DBV	5	3000	178.0	9.0	3.3	3.2	1.4	4.0	8.0	Q3
INA196AIDBVT	SOT-23	DBV	5	250	178.0	9.0	3.3	3.2	1.4	4.0	8.0	Q3
INA197AIDBVR	SOT-23	DBV	5	3000	178.0	9.0	3.3	3.2	1.4	4.0	8.0	Q3
INA197AIDBVR1G4	SOT-23	DBV	5	3000	178.0	9.0	3.3	3.2	1.4	4.0	8.0	Q3
INA197AIDBVT	SOT-23	DBV	5	250	178.0	9.0	3.3	3.2	1.4	4.0	8.0	Q3

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
INA198AIDBVR	SOT-23	DBV	5	3000	178.0	9.0	3.3	3.2	1.4	4.0	8.0	Q3
INA198AIDBVRG4	SOT-23	DBV	5	3000	178.0	9.0	3.3	3.2	1.4	4.0	8.0	Q3
INA198AIDBVT	SOT-23	DBV	5	250	178.0	9.0	3.3	3.2	1.4	4.0	8.0	Q3

TAPE AND REEL BOX DIMENSIONS


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
INA193AIDBVR	SOT-23	DBV	5	3000	210.0	185.0	35.0
INA193AIDBVR1G4	SOT-23	DBV	5	3000	180.0	180.0	18.0
INA193AIDBVT	SOT-23	DBV	5	250	210.0	185.0	35.0
INA194AIDBVR	SOT-23	DBV	5	3000	208.0	191.0	35.0
INA194AIDBVR1G4	SOT-23	DBV	5	3000	180.0	180.0	18.0
INA194AIDBVT	SOT-23	DBV	5	250	180.0	180.0	18.0
INA194AIDBVT	SOT-23	DBV	5	250	210.0	185.0	35.0
INA195AIDBVR	SOT-23	DBV	5	3000	210.0	185.0	35.0
INA195AIDBVRG4	SOT-23	DBV	5	3000	180.0	180.0	18.0
INA195AIDBVT	SOT-23	DBV	5	250	210.0	185.0	35.0
INA196AIDBVR	SOT-23	DBV	5	3000	180.0	180.0	18.0
INA196AIDBVR1G4	SOT-23	DBV	5	3000	180.0	180.0	18.0
INA196AIDBVT	SOT-23	DBV	5	250	180.0	180.0	18.0
INA197AIDBVR	SOT-23	DBV	5	3000	180.0	180.0	18.0
INA197AIDBVR1G4	SOT-23	DBV	5	3000	180.0	180.0	18.0
INA197AIDBVT	SOT-23	DBV	5	250	180.0	180.0	18.0
INA198AIDBVR	SOT-23	DBV	5	3000	180.0	180.0	18.0
INA198AIDBVRG4	SOT-23	DBV	5	3000	180.0	180.0	18.0

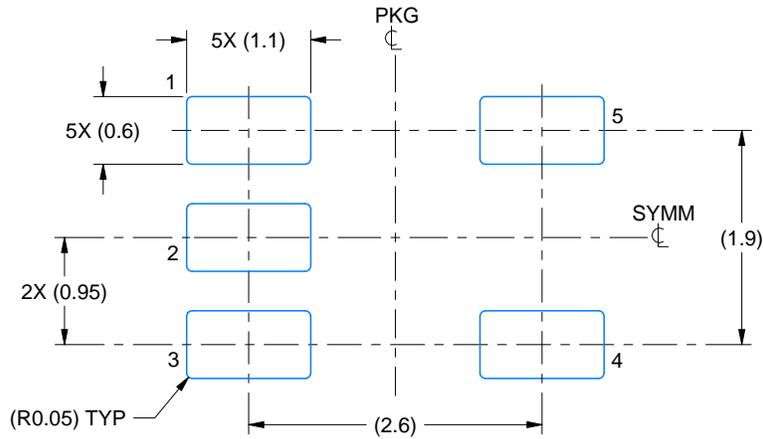
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
INA198AIDBVT	SOT-23	DBV	5	250	180.0	180.0	18.0

EXAMPLE BOARD LAYOUT

DBV0005A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:15X



SOLDER MASK DETAILS

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NOTES: (continued)

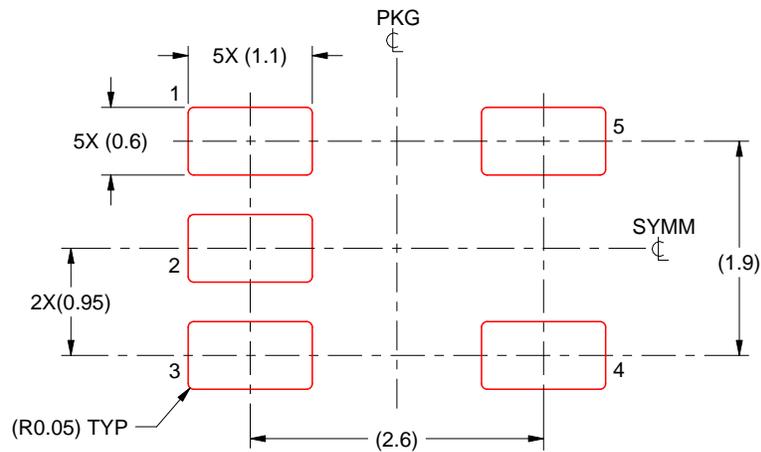
- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DBV0005A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:15X

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NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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